



#### 60V NPN ULTRA-LOW VCE(sat) TRANSISTOR IN PowerDI3333-8

#### **Features**

- BVcEo > 60V
- BV<sub>EBO</sub> > 8V
- Continuous Current Ic to 6A
- Peak Pulse Current Icm to 12A
- Ultra-Low Saturation Voltage V<sub>CE(sat)</sub> < 45mV @ 1A</li>
- High Current RcE(sat) = 23mΩ Typical
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Wettable Flank for Improved Optical Inspection
- Rated to +175°C Ideal for High-Temperature Environments
- Complementary PNP Type: <u>DXTP78060DFG</u>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under a separate datasheet (DXTN78060DFGQ)

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>3333-8
- Package Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin.
   Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)

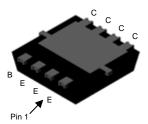
## **Applications**

- MOSFET & IGBT gate drivers
- Load switches
- Low-voltage regulation
- DC to DC converters
- Motor, solenoid, relay and actuator drivers control

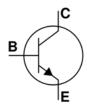
#### PowerDI3333-8/SWP (Type UX)







**Bottom View** 



Device Symbol

## **Ordering Information** (Note 4)

Orderable Part Number	Dookogo	Parkage Marking Book Sire (inches) T		Tape Width (mm)	Packing	
Orderable Part Number	Package	Marking	Reel Size (inches)	rape widin (ililii)	Qty.	Carrier
DXTN78060DFG-7	PowerDI3333-8/SWP (Type UX)	2Y0	7	12	2,000	Reel

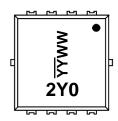
Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- and <1000ppm antimony compounds.

  4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**

PowerDI3333-8/SWP (Type UX)



2Y0 = Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 25 = 2025)

WW = Week Code (01 to 53)



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	100	V
Collector-Emitter Voltage	VCEO	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	8	V
Continuous Collector Current (Note 5)	Ic	3	Α
Continuous Collector Current (Note 7)	Ic	6	Α
Peak Pulse Current	Ісм	12	Α

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		900	mW
Power Dissipation	(Note 6)	PD	1.6	W
	(Note 7)		2.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	92	°C/W
	(Note 7)		62.5	°C/W
Thermal Resistance, Junction to Case (Note	Rejc	8	°C/W	
Thermal Resistance, Junction to Lead (Note	ReJL	6.5	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C	

## ESD Ratings (Note 9)

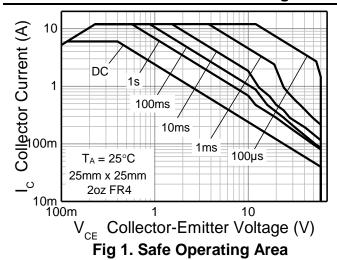
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	IV

Notes: 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady state.

- 6. Same as Note 5, except the device is mounted on 15mm x 15mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- 8. Thermal resistance from junction to solder-point (at the collector tab).
- 9. Refer to JEDEC specification JESD22-A114, JESD22-A115 and JESD22-C101.



#### **Thermal Characteristics and Derating Information**



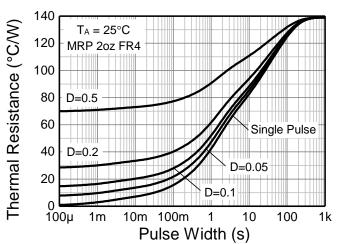


Fig 2. Transient Thermal Impedance

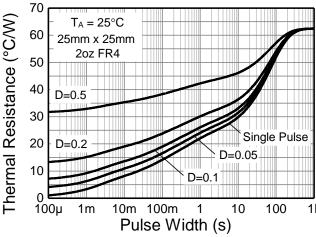


Fig 3. Transient Thermal Impedance

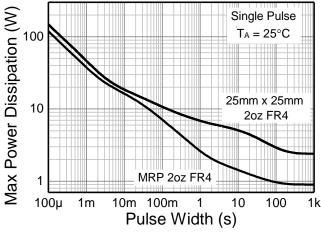


Fig 4. Pulse Power Dissipation

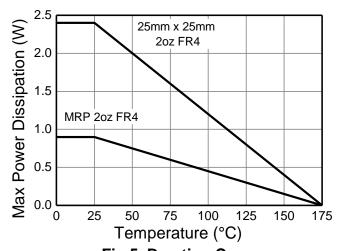


Fig 5. Derating Curve



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	100	_	_	V	Ic = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BVceo	60		_	V	Ic = 10mA
Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	5	_	_	V	I <sub>E</sub> = 100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	8	_	_	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	Ісво	_	_	100	nA	V <sub>CB</sub> = 100V
Collector Cut-on Current		_	_	10	μA	V <sub>CB</sub> = 100V, T <sub>A</sub> = +125°C
Collector Cut-off Current	I <sub>CES</sub>	_	_	300	nA	V <sub>CE</sub> = 48V
Emitter Cut-off Current	IEBO	_	_	50	nA	V <sub>EB</sub> = 7V
		_	55	_	mV	Ic = 100mA, I <sub>B</sub> = 1mA
		_	65	100	mV	$I_C = 1A$ , $I_B = 20mA$
Collector Emitter Seturation Valtage (Note 10)	1/	_	30	45	mV	Ic = 1A, I <sub>B</sub> = 100mA
Collector-Emitter Saturation Voltage (Note 10)	VCE(sat)	_	110	145	mV	Ic = 2A, I <sub>B</sub> = 40mA
		_	85	125	mV	Ic = 3A, I <sub>B</sub> = 150mA
		_	135	170	mV	$I_C = 6A$ , $I_B = 600mA$
Dogo Emitter Seturation Voltage (Note 10)	VBE(sat)	_	870	1,000	mV	Ic = 3A, I <sub>B</sub> = 150mA
Base-Emitter Saturation Voltage (Note 10)		_	1	1.1	V	Ic = 6A, I <sub>B</sub> = 600mA
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(on)</sub>	_	765	850	mV	I <sub>C</sub> = 3A, V <sub>CE</sub> = 2V
Base-Emilier Furn-On Voltage (Note 10)		_	845	950	mV	I <sub>C</sub> = 6A, V <sub>CE</sub> = 2V
	h <sub>FE</sub>	250	370	_		Ic = 10mA, VcE = 2V
		300	370	550		Ic = 100mA, VcE = 2V
DC Current Gain (Note 10)		240	340	_	1	I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
DC Current Gain (Note 10)		180	290	_		Ic = 2A, VcE = 2V
		100	170	_		IC = 3A, VCE = 2V
		25	55	_	_	Ic = 6A, VcE = 2V
Input Capacitance	C <sub>ibo</sub>	_	350	_	pF	V <sub>EB</sub> = 0.5V, f = 1MHz
Output Capacitance	Cobo	_	18	_	pF	V <sub>CB</sub> = 10V, f = 1MHz
Current Gain-Bandwidth Product	f⊤	150	250	_	MHz	VcE = 10V, Ic = 100mA, f = 50MHz
Turn-On Time	td	_	11.5		ns	
Tuiti-Oil Tiille	t <sub>r</sub>	_	75		ns	Vcc = 10V, Ic = 3A,
Turn-Off Time	ts	_	295	_	ns	$I_{B1} = -I_{B2} = 300 \text{mA}$
Tulli-Oil Tillie	t <sub>f</sub>		30	_	ns	

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

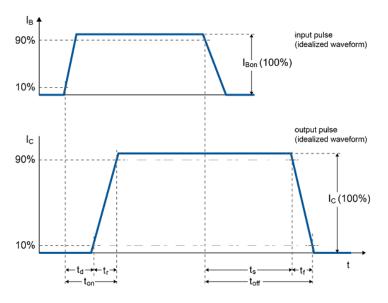
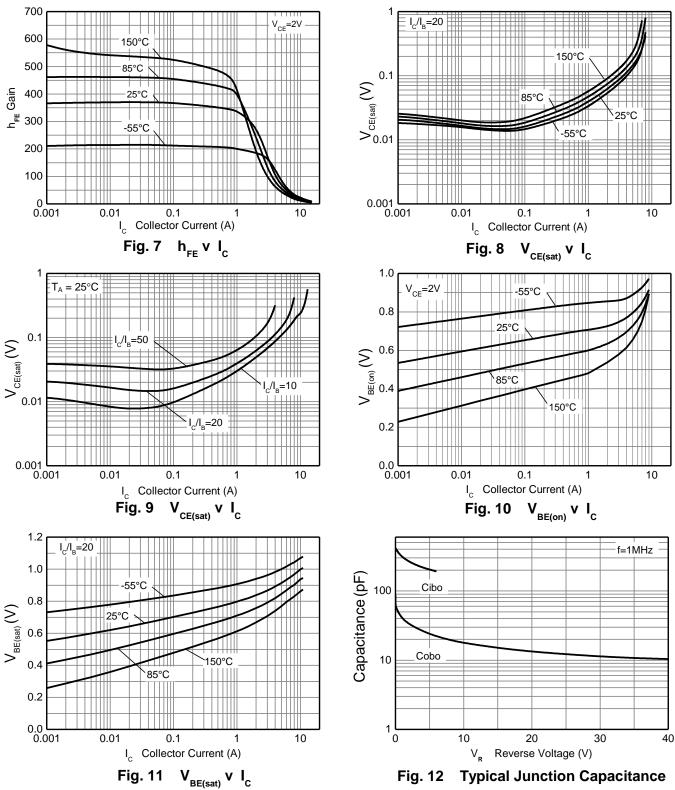


Fig 6. Timing Waveform



#### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



**Typical Junction Capacitance** Fig. 12



# Typical Electrical Characteristics (continued) (@TA = +25°C, unless otherwise specified.)

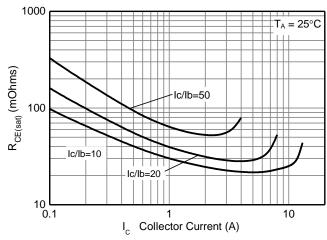


Fig. 13  $R_{CE(sat)} v I_{C}$ 

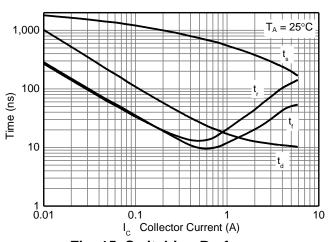


Fig. 15 Switching Performance

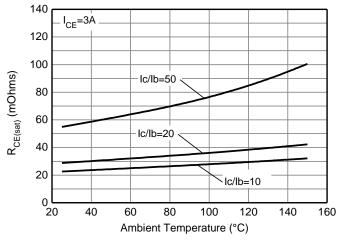


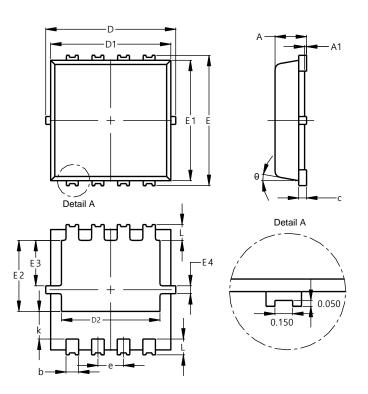
Fig. 14 R<sub>CE(sat)</sub> v T<sub>A</sub>



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8/SWP (Type UX)

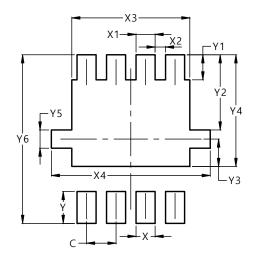


PowerDI3333-8/SWP					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
q	0.25	0.40	0.32		
C	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
П	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
Ф	-	_	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8/SWP (Type UX)



Dimensions	Value (in mm)
С	0.650
Χ	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: 11. Side wall tin plated package for wettable flanks in AOI



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